



### **RSS110N03FU6TB Information**



For Reference Only

Part Number RSS110N03FU6TB

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

**Description**MOSFET N-CH 30V 11A 8SOIC**Package**8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **RSS110N03FU6TB Specifications**

Manufacturer Part Number         RSS110N03FU6TB           Manufacturer         Rohm Semiconductor           Category         Discrete Semiconductor Products           Transistors - FETs, MOSFETs - Single           Package         8-SOIC (0.154", 3.90mm Width)           Series         -           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         11A (Ta)           Drive Voltage (Max Rds On, Min Rds On)         4V, 10V           Vgs(th) (Max) @ Id         2.5V @ ImA           Gate Charge (Qg) (Max) @ Vgs         17nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         1300pF @ 10V           Vgs (Max)         2V           FET Feature         -           Power Dissipation (Max)         2W (Ta)           Rds On (Max) @ Id, Vgs         10.7 mOhm @ 11A, 10V           Operating Temperature         150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         8-SOP           Package / Case         8-SOIC (0.154", 3.90mm Width)		
CategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - SinglePackage8-SOIC (0.154", 3.90mm Width)Series-FET TypeN-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C11A (Ta)Drive Voltage (Max Rds On, Min Rds On)4V, 10VVgs(th) (Max) @ Id2.5V @ 1mAGate Charge (Qg) (Max) @ Vgs17nC @ 5VInput Capacitance (Ciss) (Max) @ Vds1300pF @ 10VVgs (Max)20VFET Feature-Power Dissipation (Max)2W (Ta)Rds On (Max) @ Id, Vgs10.7 mohm @ 11A, 10VOperating Temperature150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPPackage / Case8-SOIC (0.154", 3.90mm Width)	Manufacturer Part Number	RSS110N03FU6TB
Package         8-SOIC (0.154", 3.90mm Width)           Series         -           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         11A (Ta)           Drive Voltage (Max Rds On, Min Rds On)         4V, 10V           Vgs(th) (Max) @ Id         2.5V @ ImA           Gate Charge (Qg) (Max) @ Vgs         17nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         1300pF @ 10V           Vgs (Max)         20V           FET Feature         -           Power Dissipation (Max)         2W (Ta)           Rds On (Max) @ Id, Vgs         10.7 mOhm @ 11A, 10V           Operating Temperature         150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         8-SOP           Package / Case         8-SOIC (0.154", 3.90mm Width)	Manufacturer	Rohm Semiconductor
Package         8-SOIC (0.154", 3.90mm Width)           Series         -           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         11A (Ta)           Drive Voltage (Max Rds On, Min Rds On)         4V, 10V           Vgs(th) (Max) @ Id         2.5V @ ImA           Gate Charge (Qg) (Max) @ Vgs         17nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         1300pF @ 10V           Vgs (Max)         20V           FET Feature         -           Power Dissipation (Max)         2W (Ta)           Rds On (Max) @ Id, Vgs         10.7 mOhm @ 11A, 10V           Operating Temperature         150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         8-SOP           Package / Case         8-SOIC (0.154", 3.90mm Width)	Category	Discrete Semiconductor Products
Series - N-Channel  Technology MOSFET (Metal Oxide)  Drain to Source Voltage (Vdss) 30V  Current - Continuous Drain (Id) @ 25°C 11A (Ta)  Drive Voltage (Max Rds On, Min Rds On) 4V, 10V  Vgs(th) (Max) @ Id 2.5V @ 1mA  Gate Charge (Qg) (Max) @ Vgs 17nC @ 5V  Input Capacitance (Ciss) (Max) @ Vds 1300pF @ 10V  Vgs (Max) 20V  FET Feature - Power Dissipation (Max) 2W (Ta)  Rds On (Max) @ Id, Vgs 10.7 mOhm @ 11A, 10V  Operating Temperature 150°C (TJ)  Mounting Type Surface Mount  Supplier Device Package 8-SOP  Package / Case 8-SOIC (0.154", 3.90mm Width)		Transistors - FETs, MOSFETs - Single
FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 11A (Ta) Drive Voltage (Max Rds On, Min Rds On) 4V, 10V Vgs(th) (Max) @ Id 2.5V @ 1mA Gate Charge (Qg) (Max) @ Vgs 17nC @ 5V Input Capacitance (Ciss) (Max) @ Vds 1300pF @ 10V Vgs (Max) 20V FET Feature - Power Dissipation (Max) 2W (Ta) Rds On (Max) @ Id, Vgs 10.7 mOhm @ 11A, 10V Operating Temperature 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SOP Package / Case 8-SOIC (0.154", 3.90mm Width)	Package	8-SOIC (0.154", 3.90mm Width)
Technology  Drain to Source Voltage (Vdss)  Current - Continuous Drain (Id) @ 25°C  11A (Ta)  Drive Voltage (Max Rds On, Min Rds On)  Vgs(th) (Max) @ Id  Gate Charge (Qg) (Max) @ Vgs  17nC @ 5V  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  Vgs (Max)  Vgs (Max)  20V  FET Feature  - Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  Package / Case  8-SOIC (0.154", 3.90mm Width)	Series	-
Drain to Source Voltage (Vdss)  Current - Continuous Drain (Id) @ 25°C  11A (Ta)  Drive Voltage (Max Rds On, Min Rds On)  Vgs(th) (Max) @ Id  Cate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  Vgs (Max)  Vgs (Max)  Vgs (Max)  Vgs (Max)  ET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  Package / Case  30V  11A (Ta)  11A (Ta)	FET Type	N-Channel
Current - Continuous Drain (Id) @ 25°C 11A (Ta)  Drive Voltage (Max Rds On, Min Rds On) 4V, 10V  Vgs(th) (Max) @ Id 2.5V @ 1mA  Gate Charge (Qg) (Max) @ Vgs 17nC @ 5V  Input Capacitance (Ciss) (Max) @ Vds 1300pF @ 10V  Vgs (Max) 20V  FET Feature - Power Dissipation (Max) 2W (Ta)  Rds On (Max) @ Id, Vgs 10.7 mOhm @ 11A, 10V  Operating Temperature 150°C (TJ)  Mounting Type Surface Mount  Supplier Device Package 8-SOP  Package / Case 8-SOIC (0.154", 3.90mm Width)	Technology	MOSFET (Metal Oxide)
Drive Voltage (Max Rds On, Min Rds On)  Vgs(th) (Max) @ Id  Cate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  Vgs (Max)  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  Inord Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  Package / Case  4V, 10V  2.5V @ ImA  17nC @ 5V  1300pF @ 10V  20V  FET Feature  -  10.7 mOhm @ 11A, 10V  10.7 mOhm @ 11A, 10V  150°C (TJ)  Surface Mount  Supplier Device Package  8-SOP  Package / Case  8-SOIC (0.154", 3.90mm Width)	Drain to Source Voltage (Vdss)	30V
Vgs(th) (Max) @ Id  Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  Vgs (Max)  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  Package / Case  8-SOIC (0.154", 3.90mm Width)	Current - Continuous Drain (Id) @ 25°C	11A (Ta)
Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  1300pF @ 10V  Vgs (Max)  20V  FET Feature  - Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  Package / Case  8-SOIC (0.154", 3.90mm Width)	Drive Voltage (Max Rds On, Min Rds On)	4V, 10V
Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  8-SOP  Package / Case  8-SOIC (0.154", 3.90mm Width)	Vgs(th) (Max) @ Id	2.5V @ 1mA
Vgs (Max)  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  8-SOP  Package / Case  8-SOIC (0.154", 3.90mm Width)	Gate Charge (Qg) (Max) @ Vgs	17nC @ 5V
FET Feature - Power Dissipation (Max) 2W (Ta) Rds On (Max) @ Id, Vgs 10.7 mOhm @ 11A, 10V Operating Temperature 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SOP Package / Case 8-SOIC (0.154", 3.90mm Width)	Input Capacitance (Ciss) (Max) @ Vds	1300pF @ 10V
Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  10.7 mOhm @ 11A, 10V  Operating Temperature  150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  8-SOP  Package / Case  8-SOIC (0.154", 3.90mm Width)	Vgs (Max)	20V
Rds On (Max) @ Id, Vgs10.7 mOhm @ 11A, 10VOperating Temperature150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPPackage / Case8-SOIC (0.154", 3.90mm Width)	FET Feature	-
Operating Temperature 150°C (TJ)  Mounting Type Surface Mount  Supplier Device Package 8-SOP  Package / Case 8-SOIC (0.154", 3.90mm Width)	Power Dissipation (Max)	2W (Ta)
Mounting Type Surface Mount Supplier Device Package 8-SOP Package / Case 8-SOIC (0.154", 3.90mm Width)	Rds On (Max) @ Id, Vgs	10.7 mOhm @ 11A, 10V
Supplier Device Package 8-SOP Package / Case 8-SOIC (0.154", 3.90mm Width)	Operating Temperature	150°C (TJ)
Package / Case 8-SOIC (0.154", 3.90mm Width)	Mounting Type	Surface Mount
	Supplier Device Package	8-SOP
Report errors?	Package / Case	8-SOIC (0.154", 3.90mm Width)
		Report errors?

### **RSS110N03FU6TB Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

# **RSS110N03FU6TB Payment Methods**





















### RSS110N03FU6TB Shipping Methods













If you have any question about RSS110N03FU6TB, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com